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## SN54LVTH16373, SN74LVTH16373 3.3-V ABT 16-BIT TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

SCBS144O-MAY 1992-REVISED OCTOBER 2005

#### **FEATURES**

- Members of the Texas Instruments Widebus™
  Family
- State-of-the-Art Advanced BiCMOS
   Technology (ABT) Design for 3.3-V Operation
   and Low Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V<sub>CC</sub>)
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- I<sub>off</sub> and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Distributed V<sub>CC</sub> and GND Pins Minimize High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)

#### SN54LVTH16373... WD PACKAGE SN74LVTH16373... DGG OR DL PACKAGE (TOP VIEW)

1 <del>OE</del> [	1	$\cup$	48	] 1LE
1Q1 [	2		47	] 1D1
1Q2 [	3		46	] 1D2
GND [	4		45	GND
1Q3 [	5		44	] 1D3
1Q4 [	6		43	] 1D4
V <sub>CC</sub> [	7		42	] v <sub>cc</sub>
1Q5 [	8		41	] 1D5
1Q6	9		40	] 1D6
GND [	10		39	GND
1Q7 [	11		38	] 1D7
1Q8 [	12		37	] 1D8
2Q1 [	13		36	] 2D1
2Q2 [	14		35	2D2
GND [	15		34	GND
2Q3 [	16		33	] 2D3
2Q4 [	17		32	2D4
v <sub>cc</sub> [	18		31	] v <sub>cc</sub>
2Q5 [	19		30	2D5
2Q6 [	20		29	2D6
GND [	21		28	GND
2Q7 [	22		27	2D7
2Q8 [	23		26	] 2D8
2 <del>OE</del>	24		25	] 2LE
	1			

#### **DESCRIPTION/ORDERING INFORMATION**

The 'LVTH16373 devices are 16-bit transparent D-type latches with 3-state outputs designed for low-voltage (3.3-V)  $V_{CC}$  operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE	(1)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	FBGA – GRD	Tone and real	SN74LVTH16373GRDR	11.272
	FBGA – ZRD (Pb-free)	Tape and reel	SN74LVTH16373ZRDR	LL373
	SSOP – DL	Tube	SN74LVTH16373DL	LVTH16373
–40°C to 85°C	330F - DL	Tape and reel	SN74LVTH16373DLR	LV11103/3
	TSSOP - DGG	Tape and reel	SN74LVTH16373DGGR	LVTH16373
	VFBGA – GQL	Tone and real	SN74LVTH16373GQLR	11.272
	VFBGA – ZQL (Pb-free)	Tape and reel	SN74LVTH16373ZQLR	LL373
–55°C to 125°C	CFP – WD	Tube	SNJ54LVTH16373WD	SNJ54LVTH16373WD

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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SCBS144O-MAY 1992-REVISED OCTOBER 2005



### DESCRIPTION/ORDERING INFORMATION (CONTINUED)

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

When  $V_{CC}$  is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using  $I_{off}$  and power-up 3-state. The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

# GQL OR ZQL PACKAGE (TOP VIEW)

		1	2	3	4	5	6_
Α	$^{\prime}$	()	()	()		()	$\circ$
В		()	()	()	()	()	()
С		()	()	()	()	()	()
D		()	()	()	()	()	()
Е		()	()			()	()
F		()	()			()	()
G		()	()	()	()	()	()
Н		()	()	()	()	()	()
J		()	()	()	()	()	()
K	l	()	()	()	()	()	0
	•						_

# TERMINAL ASSIGNMENTS<sup>(1)</sup> (56-Ball GQL/ZQL Package)

	1	2	3	4	5	6
Α	1 <del>OE</del>	NC	NC	NC	NC	1CLK
В	1Q2	1Q1	GND	GND	1D1	1D2
С	1Q4	1Q3	V <sub>CC</sub>	$V_{CC}$	1D3	1D4
D	1Q6	1Q5	GND	GND	1D5	1D6
E	1Q8	1Q7			1D7	1D8
F	2Q1	2Q2			2D2	2D1
G	2Q3	2Q4	GND	GND	2D4	2D3
Н	2Q5	2Q6	V <sub>CC</sub>	V <sub>CC</sub>	2D6	2D5
J	2Q7	2Q8	GND	GND	2D8	2D7
K	2 <del>OE</del>	NC	NC	NC	NC	2CLK

(1) NC – No internal connection



SCBS144O-MAY 1992-REVISED OCTOBER 2005

#### **GRD OR ZRD PACKAGE** (TOP VIEW) 2 3 4 5 000000Α 000000 В 000000 С 000000 D 000000 Ε 000000 F 000000 G 000000 Н 000000

# TERMINAL ASSIGNMENTS<sup>(1)</sup> (54-Ball GRD/ZRD Package)

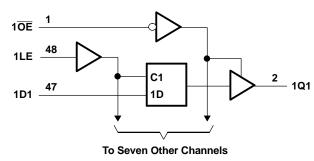
	1	2	3	4	5	6
Α	1Q1	NC	1 <del>OE</del>	1LE	NC	1D1
В	1Q3	1Q2	NC	NC	1D2	1D3
С	1Q5	1Q4	$V_{CC}$	V <sub>CC</sub>	1D4	1D5
D	1Q7	1Q6	GND	GND	1D6	1D7
E	2Q1	1Q8	GND	GND	1D8	2D1
F	2Q3	2Q2	GND	GND	2D2	2D3
G	2Q5	2Q4	$V_{CC}$	V <sub>CC</sub>	2D4	2D5
Н	2Q7	2Q6	NC	NC	2D6	2D7
J	2Q8	NC	2 <del>OE</del>	2LE	NC	2D8

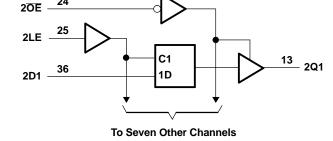
(1) NC - No internal connection

# FUNCTION TABLE (8-BIT SECTION)

	INPUTS							
ŌĒ	CLK	D	Q					
L	Н	Н	Н					
L	Н	L	L					
L	L	Χ	$Q_0$					
Н	Χ	Χ	Z					

#### **LOGIC DIAGRAM (POSITIVE LOGIC)**





Pin numbers shown are for the DGG, DL, and WD packages.

SCBS144O-MAY 1992-REVISED OCTOBER 2005



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	4.6	V
$V_{I}$	Input voltage range (2)		-0.5	7	V
Vo	Voltage range applied to any output in the high-in	npedance or power-off state(2)	-0.5	7	V
Vo	Voltage range applied to any output in the high st	tate <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
	Comment into any system that has been state	SN54LVTH16373		96	A
I <sub>O</sub>	Current into any output in the low state	SN74LVTH16373		128	mA
		SN54LVTH16373		48	0
I <sub>O</sub>	Current into any output in the high state (3)	SN74LVTH16373		64	mA
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
		DGG package		70	
0	Declines the word in a decree (4)	DL package		63	°C
$\theta_{JA}$	Package thermal impedance (4)	GQL/ZQL package		42	°C
		GRD/ZRD package		36	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## Recommended Operating Conditions<sup>(1)</sup>

			SN54LVTI	116373	SN74LVTH	16373	LINUT
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.7	3.6	2.7	3.6	٧
V <sub>IH</sub>	High-level input voltage		2		2		V
V <sub>IL</sub>	Low-level input voltage			0.8		0.8	٧
$V_{I}$	Input voltage			5.5		5.5	V
I <sub>OH</sub>	High-level output current			-24		-32	mA
I <sub>OL</sub>	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outpts enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T <sub>A</sub>	Operating free-air temperature		-55	125	-40	85	°C

All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed. This current flows only when the output is in the high state and  $V_O > V_{CC}$ . The package thermal impedance is calculated in accordance with JESD 51-7.

SCBS144O-MAY 1992-REVISED OCTOBER 2005

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

DADA	METER	TEST OF	ANDITIONS	SN54	LVTH1637	3	SN74L	VTH1637	73	LIMIT
PARA	METER	IESI CC	ONDITIONS	MIN	TYP <sup>(1)</sup>	MAX	MIN	TYP <sup>(1)</sup>	MAX	UNIT
V <sub>IK</sub>		$V_{CC} = 2.7 \text{ V},$	I <sub>I</sub> = -18 mA			-1.2			-1.2	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V},$	$I_{OH} = -100 \mu A$	V <sub>CC</sub> - 0.2			V <sub>CC</sub> - 0.2			
.,		V <sub>CC</sub> = 2.7 V,	$I_{OH} = -8 \text{ mA}$	2.4			2.4			V
$V_{OH}$		V 2.V	$I_{OH} = -24 \text{ mA}$	2						V
		$V_{CC} = 3 V$	$I_{OH} = -32 \text{ mA}$				2			
		V 07V	I <sub>OL</sub> = 100 μA			0.2			0.2	
		$V_{CC} = 2.7 \text{ V}$	I <sub>OL</sub> = 24 mA			0.5			0.5	
.,			I <sub>OL</sub> = 16 mA			0.4			0.4	V
$V_{OL}$			I <sub>OL</sub> = 32 mA			0.5			0.5	V
		$V_{CC} = 3 V$	I <sub>OL</sub> = 48 mA			0.55				
			I <sub>OL</sub> = 64 mA						0.55	
		$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V <sub>I</sub> = 5.5 V			10			10	
I <sub>I</sub>	Control inputs	V <sub>CC</sub> = 3.6 V,	V <sub>I</sub> = V <sub>CC</sub> or GND			±1			±1	μΑ
•	Data	V <sub>CC</sub> = 3.6 V	$V_I = V_{CC}$			1			1	·
	inputs		$V_1 = 0$			<b>–</b> 5			<b>-</b> 5	
I <sub>off</sub>		$V_{CC} = 0$ ,	$V_1$ or $V_0 = 0$ to 4.5 V						±100	μΑ
		V 2.V	V <sub>I</sub> = 0.8 V	75			75			
I <sub>I(hold)</sub>	Data inputs	V <sub>CC</sub> = 3 V	V <sub>I</sub> = 2 V	-75			<b>–75</b>			μΑ
	прац	$V_{CC} = 3.6 \text{ V},^{(2)}$	V <sub>I</sub> = 0 to 3.6 V			±500		±500		
I <sub>OZH</sub>		$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 3 V			5			5	μΑ
I <sub>OZL</sub>		$V_{CC} = 3.6 \text{ V},$	V <sub>O</sub> = 0.5 V			-5			-5	μΑ
I <sub>OZPU</sub>		$\frac{V_{CC}}{OE} = 0$ to 1.5 V, $V_{O} = 0$	0.5 V to 3 V,			±100 <sup>(3)</sup>			±100	μΑ
I <sub>OZPD</sub>		$\frac{V_{CC}}{OE}$ = 1.5 V to 0, $V_{O}$ = $\frac{V_{CC}}{OE}$ = don't care	0.5 V to 3 V,			±100 <sup>(3)</sup>			±100	μΑ
		V <sub>CC</sub> = 3.6 V,	Outputs high			0.19			0.19	
I <sub>CC</sub>		$I_{O} = 0$ ,	Outputs low			5			5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			0.19			0.19	
ΔI <sub>CC</sub> <sup>(4)</sup>		$V_{CC} = 3 \text{ V to } 3.6 \text{ V, One}$ Other inputs at $V_{CC}$ or $0$	e input at V <sub>CC</sub> – 0.6 V, GND			0.2			0.2	mA
$C_{i}$		V <sub>I</sub> = 3 V or 0			3			3		pF
C <sub>o</sub>		V <sub>O</sub> = 3 V or 0			9			9		pF

All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

On products compliant to MIL-PRF-38535, this parameter is not production tested.

<sup>(4)</sup> This is the increase in supply current for each input that is at the specified TTL voltage level, rather than  $V_{CC}$  or GND.

SCBS144O-MAY 1992-REVISED OCTOBER 2005



#### **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		S	SN54LVTH16373				SN74LVTH16373				
		$V_{CC}$ = 3.3 V $\pm$ 0.3 V		V <sub>CC</sub> = 2.7 V		$V_{CC}$ = 3.3 V $\pm$ 0.3 V		V <sub>CC</sub> = 2.7 V		UNIT	
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t <sub>w</sub>	Pulse duration, LE high	3		3		3		3		ns	
t <sub>su</sub>	Setup time, data before LE↓	2		2		1		0.6		ns	
t <sub>h</sub>	Hold time, data after LE↓	3		3.3		1		1.1		ns	

## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

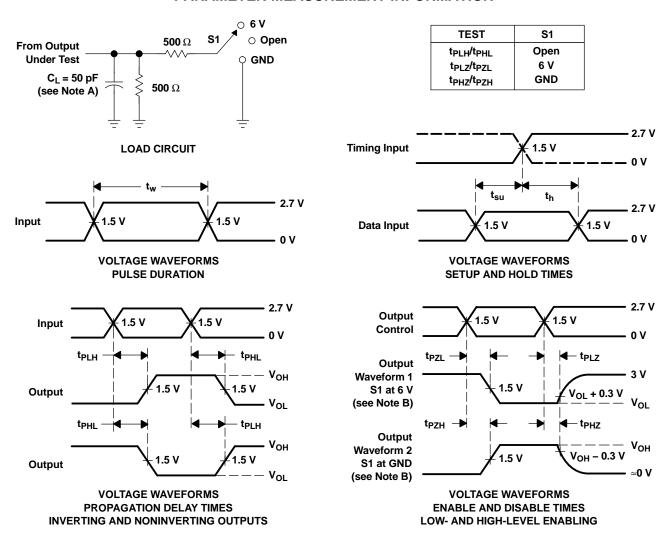
			SN54LVTH16373					SN74I	LVTH1	6373		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$ = 3.3 V $\pm$ 0.3 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		V	V <sub>CC</sub> = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP <sup>(1)</sup>	MAX	MIN	MAX	
t <sub>PLH</sub>	D	Q	1.4	4.5		5.2	1.5	2.7	3.8		4.2	ne
t <sub>PHL</sub>	D	3	1.4	4.4		4.8	1.5	2.5	3.6		4	ns
t <sub>PLH</sub>	LE	Q	1.8	5.5		5.8	2.1	3	4.3		4.8	ns
t <sub>PHL</sub>	LE	Q	1.8	5.2		5.6	2.1	2.9	4		4	113
t <sub>PZH</sub>	ŌĒ	Q	1.4	5.7		6.7	1.5	2.8	4.3		5.1	no
t <sub>PZL</sub>	OE	Q	1.4	5.5		6	1.5	2.8	4.3		4.7	ns
t <sub>PHZ</sub>	ŌĒ	0	2	6		6.2	2.4	3.5	5		5.4	
t <sub>PLZ</sub>	OE	Q	1.4	5.2		5.6	2	3.2	4.7		4.8	ns
t <sub>sk(o)</sub>									0.5			ns

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C.



SCBS144O-MAY 1992-REVISED OCTOBER 2005

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2.5 ns.  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-9681001QXA	ACTIVE	CFP	WD	48	1	TBD	Call TI	Level-NC-NC-NC
74LVTH16373DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVTH16373DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVTH16373DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVTH16373DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVTH16373GQLR	ACTIVE	VFBGA	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74LVTH16373GRDR	ACTIVE	LFBGA	GRD	54	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74LVTH16373ZQLR	ACTIVE	VFBGA	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74LVTH16373ZRDR	ACTIVE	LFBGA	ZRD	54	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SNJ54LVTH16373WD	ACTIVE	CFP	WD	48	1	TBD	Call TI	Level-NC-NC-NC

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### WD (R-GDFP-F\*\*)

#### **CERAMIC DUAL FLATPACK**

#### **48 LEADS SHOWN**



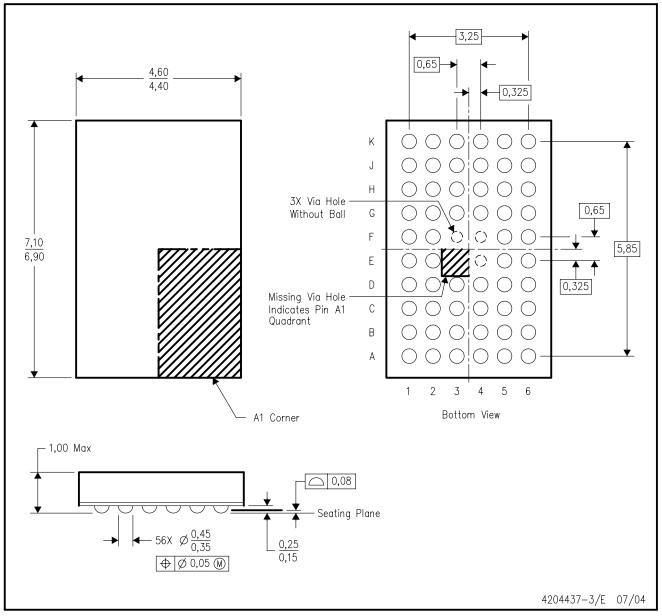
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only
- E. Falls within MIL STD 1835: GDFP1-F48 and JEDEC MO-146AA

GDFP1-F56 and JEDEC MO-146AB

# ZQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



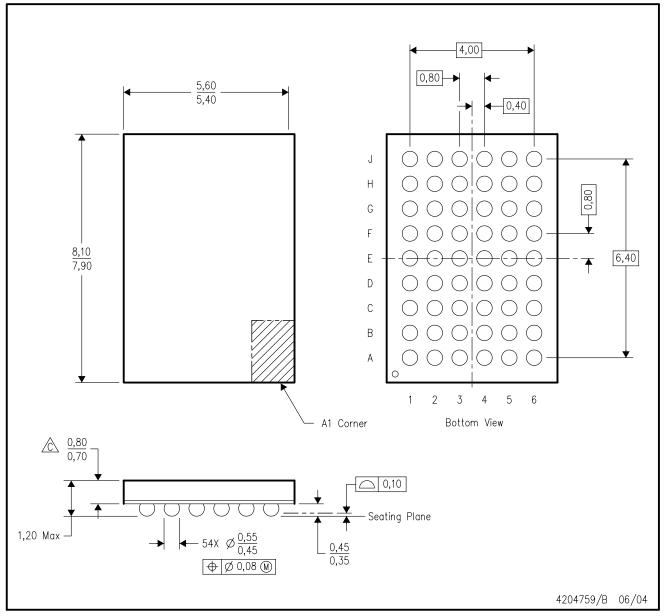
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



# GRD (R-PBGA-N54)

## PLASTIC BALL GRID ARRAY



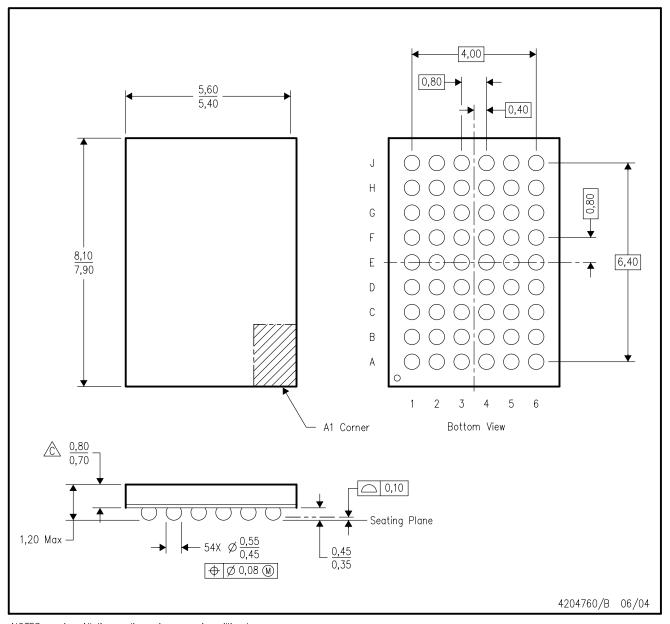
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- Falls within JEDEC MO-205 variation DD.
- D. This package is tin-lead (SnPb). Refer to the 54 ZRD package (drawing 4204760) for lead-free.



# ZRD (R-PBGA-N54)

## PLASTIC BALL GRID ARRAY



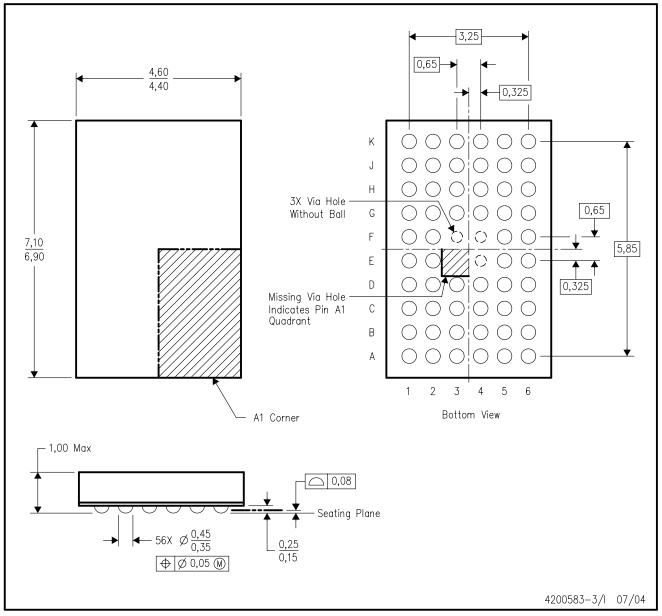
 $\hbox{NOTES:} \quad \hbox{A. All linear dimensions are in millimeters.}$ 

- B. This drawing is subject to change without notice.
- Falls within JEDEC MO-205 variation DD.
- D. This package is lead-free. Refer to the 54 GRD package (drawing 4204759) for tin-lead (SnPb).



# GQL (R-PBGA-N56)

## PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



#### DL (R-PDSO-G\*\*)

#### **48 PINS SHOWN**

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MO-118

### DGG (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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